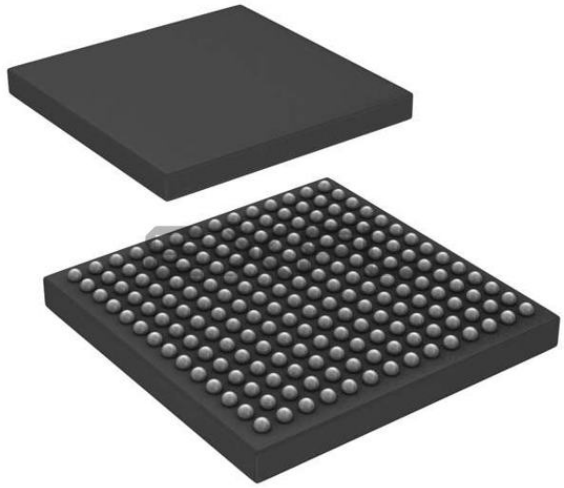
Infineon Technologies - XMC4700E196F1536AAXQMA1 Datasheet



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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	144MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I²C, LINbus, MMC/SD, SPI, UART/USART, USB OTG, USIC
Peripherals	DMA, I²S, LED, POR, Touch-Sense, WDT
Number of I/O	155
Program Memory Size	1.5MB (1.5M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	276K x 8
Voltage - Supply (Vcc/Vdd)	3.13V ~ 3.63V
Data Converters	A/D 32x12b; D/A 2x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	196-LFBGA
Supplier Device Package	PG-LFBGA-196-2
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/xmc4700e196f1536aaxqma1

2.2.1 Package Pin Summary

The following general scheme is used to describe each pin:

Table 9 Package Pin Mapping Description

Function	Package A	Package B	...	Pad Type	Notes
Name	N	Ax	...	A2	

The table is sorted by the “Function” column, starting with the regular Port pins (Px.y), followed by the dedicated pins (i.e. PORST) and supply pins.

The following columns, titled with the supported package variants, lists the package pin number to which the respective function is mapped in that package.

The “Pad Type” indicates the employed pad type (A1, A1+, A2, special=special pad, In=input pad, AN/DIG_IN=analog and digital input, Power=power supply). Details about the pad properties are defined in the Electrical Parameters.

In the “Notes”, special information to the respective pin/function is given, i.e. deviations from the default configuration after reset. Per default the regular Port pins are configured as direct input with no internal pull device active.

Table 10 Package Pin Mapping

Function	LFBGA-196	LQFP-144	LQFP-100	Pad Type	Notes
P0.0	E4	2	2	A1+	
P0.1	E3	1	1	A1+	
P0.2	C3	144	100	A2	
P0.3	C4	143	99	A2	
P0.4	D5	142	98	A2	
P0.5	C5	141	97	A2	
P0.6	C6	140	96	A2	
P0.7	D7	128	89	A2	After a system reset, via HWSEL this pin selects the DB.TDI function.
P0.8	C8	127	88	A2	After a system reset, via HWSEL this pin selects the DB.TRST function, with a weak pull-down active.
P0.9	F4	4	4	A2	
P0.10	D4	3	3	A1+	

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Table 12 Port I/O Functions (cont'd)

Function	Outputs						Inputs									
	ALT1	ALT2	ALT3	ALT4	HWO0	HWO1	HWI0	HWI1	Input	Input	Input	Input	Input	Input	Input	Input
P1.5	CAN. N1_TXD	U0C0. DOUT0	CCU80. OUT23	CCU81. OUT10	U0C0. DOUT0		U0C0. HWIN0		U0C0. DX0A	CAN. N0_RXDA	ERU0. 2A0	ERU1. 0A0	CCU41. IN1C	DSD. DIN2B		ECAT0. P0_RXD1A
P1.6	ECAT0. P0_TXD0	U0C0. SCLKOUT			SDMMC. DATA1_OUT	EBU. AD10	SDMMC. DATA1_IN	EBU. D10	DSD. DIN2A							
P1.7	ECAT0. P0_TXD1	U0C0. DOUT0	DSD. MCLK2	U1C1. SELO2	SDMMC. DATA2_OUT	EBU. AD11	SDMMC. DATA2_IN	EBU. D11		DSD. MCLK2A			DSD. MCLK0C			
P1.8	ECAT0. P0_TXD2	U0C0. SELO1	DSD. MCLK1	U1C1. SCLKOUT	SDMMC. DATA4_OUT	EBU. AD12	SDMMC. DATA4_IN	EBU. D12	CAN. N2_RXDA	DSD. MCLK1A			DSD. MCLK0D	DSD. MCLK2D	DSD. MCLK3D	
P1.9	U0C0. SCLKOUT	CAN. N2_TXD	DSD. MCLK0	U1C1. DOUT0	SDMMC. DATA5_OUT	EBU. AD13	SDMMC. DATA5_IN	EBU. D13		DSD. MCLK0A			DSD. MCLK1C	DSD. MCLK2C	DSD. MCLK3C	ECAT0. P0_RX_DVA
P1.10	ETH0. MDC	U0C0. SCLKOUT	CCU81. OUT21	ECAT0. LED_ERR			SDMMC. SDCD						CCU41. IN2C			ECAT0. P0_RXD2A
P1.11	ECAT0. LED_STATE_RUN	U0C0. SELO0	CCU81. OUT11	ECAT0. LED_RUN	ETH0. MDO		ETH0. MDIC						CCU41. IN3C			ECAT0. P0_RXD3A
P1.12	ETH0. TX_EN	CAN. N1_TXD	CCU81. OUT01	ECAT0. P0_LINK_ACT	SDMMC. DATA6_OUT	EBU. AD16	SDMMC. DATA6_IN	EBU. D16								
P1.13	ETH0. TXD0	U0C1. SELO3	CCU81. OUT20	ECAT0. PHY_CLK25	SDMMC. DATA7_OUT	EBU. AD17	SDMMC. DATA7_IN	EBU. D17	CAN. N1_RXDC							
P1.14	ETH0. TXD1	U0C1. SELO2	CCU81. OUT10	ECAT0. SYNC0		EBU. AD18		EBU. D18	U1C0. DX0E							
P1.15	SCU. EXTCLK	DSD. MCLK2	CCU81. OUT00	U1C0. DOUT0		EBU. AD19		EBU. D19		DSD. MCLK2B		ERU1. 1A0				ECAT0. P0_LINKB
P2.0	CAN. N0_TXD	CCU81. OUT21	DSD. CGPWMN	LEDTS0. COL1	ETH0. MDO	EBU. AD20	ETH0. MDIB	EBU. D20			ERU0. 0B3		CCU40. IN1C			
P2.1	CAN. N5_TXD	CCU81. OUT11	DSD. CGPWMP	LEDTS0. COL0	DB.TDO/ TRACESWO	EBU. AD21		EBU. D21	ETH0. CLK_RMIIA			ERU1. 0B0	CCU40. IN0C			ETH0. CLKRXA
P2.2	VADC. EMUX00	CCU81. OUT01	CCU41. OUT3	LEDTS0. LINE0	LEDTS0. EXTENDED0	EBU. AD22	LEDTS0. TSIN0A	EBU. D22	ETH0. RXD0A	U0C1. DX0A	ERU0. 1B2		CCU41. IN3A			
P2.3	VADC. EMUX01	U0C1. SELO0	CCU41. OUT2	LEDTS0. LINE1	LEDTS0. EXTENDED1	EBU. AD23	LEDTS0. TSIN1A	EBU. D23	ETH0. RXD1A	U0C1. DX2A	ERU0. 1A2	POSIF1. IN2A	CCU41. IN2A			
P2.4	VADC. EMUX02	U0C1. SCLKOUT	CCU41. OUT1	LEDTS0. LINE2	LEDTS0. EXTENDED2	EBU. AD24	LEDTS0. TSIN2A	EBU. D24	ETH0. RXERA	U0C1. DX1A	ERU0. 0B2	POSIF1. IN1A	CCU41. IN1A			
P2.5	ETH0. TX_EN	U0C1. DOUT0	CCU41. OUT0	LEDTS0. LINE3	LEDTS0. EXTENDED3	EBU. AD25	LEDTS0. TSIN3A	EBU. D25	ETH0. RXDVA	U0C1. DX0B	ERU0. 0A2	POSIF1. IN0A	CCU41. IN0A			ETH0. CRS_DVA
P2.6	U2C0. SELO4	ERU1. PDOUT3	CCU80. OUT13	LEDTS0. COL3	U2C0. DOUT3		U2C0. HWIN3		DSD. DIN1B	CAN. N1_RXDA	ERU0. 1B3	CAN. N5_RXDB	CCU40. IN3C	ECAT0. P0_RX_ERRB		
P2.7	ETH0. MDC	CAN. N1_TXD	CCU80. OUT03	LEDTS0. COL2					DSD. DIN0B			ERU1. 1B0	CCU40. IN2C			
P2.8	ETH0. TXD0	ERU1. PDOUT1	CCU80. OUT32	LEDTS0. LINE4	LEDTS0. EXTENDED4	EBU. AD26	LEDTS0. TSIN4A	EBU. D26	DAC. TRIGGER5				CCU40. IN0B	CCU40. IN1B	CCU40. IN2B	CCU40. IN3B
P2.9	ETH0. TXD1	ERU1. PDOUT2	CCU80. OUT22	LEDTS0. LINE5	LEDTS0. EXTENDED5	EBU. AD27	LEDTS0. TSIN5A	EBU. D27	DAC. TRIGGER4				CCU41. IN0B	CCU41. IN1B	CCU41. IN2B	CCU41. IN3B
P2.10	VADC. EMUX10	ERU1. PDOUT0	ECAT0. PHY_RST	ECAT0. SYNC1	DB. ETM_TRACEDATA3	EBU. AD28		EBU. D28								
P2.11	ETH0. TXER	ECAT0. P1_TXD0	CCU80. OUT22		DB. ETM_TRACEDATA2	EBU. AD29		EBU. D29								

Table 12 Port I/O Functions (cont'd)

Function	Outputs						Inputs									
	ALT1	ALT2	ALT3	ALT4	HWO0	HWO1	HWI0	HWI1	Input	Input	Input	Input	Input	Input	Input	Input
P8.9			CCU81. OUT33						ECAT0. P1_RX_ERRC							
P8.10			CCU81. OUT21						ECAT0. P1_RX_CLKC							
P8.11			CCU81. OUT11						ECAT0. P1_RX_DVC							
P9.0		U2C0. SELO0		ECAT0. SYNC0					ECAT0. LATCH0B	U2C0. DX2C	ECAT0. P1_TX_CLKC					
P9.1		U2C0. SCLKOUT		ECAT0. SYNC1					ECAT0. LATCH1B	U2C0. DX1C	ECAT0. P0_TX_CLKC					
P9.2		U2C0. SELO1		ECAT0. PHY_RST					ETH0. COLC							
P9.3		U2C0. DOUT0		ECAT0. PHY_CLK25					ETH0. CRSC							
P9.4	ECAT0. LED_STATE_RU N			ECAT0. LED_RUN						U2C0. DX0E						
P9.5		U2C0. SELO2		ECAT0. LED_ERR					ETH0. RXD2C							
P9.6		U2C0. SELO3		ECAT0. MCLK					ETH0. RXD3C							
P9.7		U2C0. SELO4			ECAT0. MDO		ECAT0. MDIC		ETH0. RXERC							
P9.8				ECAT0. P0_LINK_ACT						U2C1. DX2C						
P9.9				ECAT0. P1_LINK_ACT						U2C1. DX1C						
P9.10		U2C1. DOUT0							ECAT0. P0_LINKC							
P9.11		U2C1. SELO3							ECAT0. P1_LINKC							
P14.0									VADC. G0CH0							
P14.1									VADC. G0CH1							
P14.2									VADC. G0CH2	VADC. G1CH2						
P14.3									VADC. G0CH3	VADC. G1CH3			CAN. N0_RXDB			
P14.4									VADC. G0CH4		VADC. G2CH0				CAN. N4_RXDB	ECAT0. LATCH1A
P14.5									VADC. G0CH5		VADC. G2CH1		POSIF0. IN2B			ECAT0. LATCH0A
P14.6									VADC. G0CH6				POSIF0. IN1B		G0ORC6	ECAT0. P1_RX_CLKB
P14.7									VADC. G0CH7				POSIF0. IN0B		G0ORC7	ECAT0. P1_RXD0B

Table 15 PN-Junction Characterisitics for positive Overload

Pad Type	I_{OV} = 5 mA, T_J = -40 °C	I_{OV} = 5 mA, T_J = 150 °C
A1 / A1+	$V_{IN} = V_{DDP}$ + 1.0 V	$V_{IN} = V_{DDP}$ + 0.75 V
A2	$V_{IN} = V_{DDP}$ + 0.7 V	$V_{IN} = V_{DDP}$ + 0.6 V
AN/DIG_IN	$V_{IN} = V_{DDP}$ + 1.0 V	$V_{IN} = V_{DDP}$ + 0.75 V

Table 16 PN-Junction Characterisitics for negative Overload

Pad Type	I_{OV} = 5 mA, T_J = -40 °C	I_{OV} = 5 mA, T_J = 150 °C
A1 / A1+	$V_{IN} = V_{SS}$ - 1.0 V	$V_{IN} = V_{SS}$ - 0.75 V
A2	$V_{IN} = V_{SS}$ - 0.7 V	$V_{IN} = V_{SS}$ - 0.6 V
AN/DIG_IN	$V_{IN} = V_{DDP}$ - 1.0 V	$V_{IN} = V_{DDP}$ - 0.75 V

Table 17 Port Groups for Overload and Short-Circuit Current Sum Parameters

Group	Pins
1	P0.[15:0], P3.[15:0], P8.[11:0]
2	P14.[15:0], P15.[15:0]
3	P2.[15:0], P5.[11:0], P7[11:0]
4	P1.[15:0], P4.[7:0], P6.[6:0], P9.[11:0]

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3.2 DC Parameters

3.2.1 Input/Output Pins

The digital input stage of the shared analog/digital input pins is identical to the input stage of the standard digital input/output pins.
The Pull-up on the $\overline{\text{PORST}}$ pin is identical to the Pull-up on the standard digital input/output pins.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 20 Standard Pad Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.		Max.		
Pin capacitance (digital inputs/outputs)	C_{IO} CC	–		10	pF	
Pull-down current	$\lvert I_{PDL}\rvert$ SR	150		–	µA	1) $V_{IN} \geq 0.6 \times V_{DDP}$
		–		10	µA	2) $V_{IN} \leq 0.36 \times V_{DDP}$
Pull-Up current	$\lvert I_{PUH}\rvert$ SR	–		10	µA	2) $V_{IN} \geq 0.6 \times V_{DDP}$
		100		–	µA	1) $V_{IN} \leq 0.36 \times V_{DDP}$
Input Hysteresis for pads of all A classes[3]	$HYSA$ CC	$0.1 \times V_{DDP}$		–	V	
$\overline{\text{PORST}}$ spike filter always blocked pulse duration	t_{SF1} CC	–		10	ns	
$\overline{\text{PORST}}$ spike filter pass-through pulse duration	t_{SF2} CC	100		–	ns	
$\overline{\text{PORST}}$ pull-down current	$\lvert I_{PPD}\rvert$ CC	13		–	mA	V_{IN} = 1.0 V

1) Current required to override the pull device with the opposite logic level (“force current”). With active pull device, at load currents between force and keep current the input state is undefined.

2) Load current at which the pull device still maintains the valid logic level (“keep current”). With active pull device, at load currents between force and keep current the input state is undefined.

3) Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It can not be guaranteed that it suppresses switching due to external system noise.

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Table 21 Standard Pads Class_A1

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.		Max.		
Input leakage current	I_{OZA1} CC	-500		500	nA	0 V ≤ V_{IN} ≤ V_{DDP}
Input high voltage	V_{IHA1} SR	0.6 × V_{DDP}		V_{DDP} + 0.3	V	max. 3.6 V
Input low voltage	V_{ILA1} SR	-0.3		0.36 × V_{DDP}	V	
Output high voltage, POD[1] = weak	V_{OHA1} CC	V_{DDP} - 0.4		–	V	I_{OH} ≥ -400 µA
		2.4		–	V	I_{OH} ≥ -500 µA
Output high voltage, POD[1] = medium		V_{DDP} - 0.4		–	V	I_{OH} ≥ -1.4 mA
		2.4		–	V	I_{OH} ≥ -2 mA
Output low voltage	V_{OLA1} CC	–		0.4	V	I_{OL} ≤ 500 µA; POD[1] = weak
		–		0.4	V	I_{OL} ≤ 2 mA; POD[1] = medium
Fall time	t_{FA1} CC	–		150	ns	C_L = 20 pF; POD[1] = weak
		–		50	ns	C_L = 50 pF; POD[1] = medium
Rise time	t_{RA1} CC	–		150	ns	C_L = 20 pF; POD[1] = weak
		–		50	ns	C_L = 50 pF; POD[1] = medium

1) POD = Pin Out Driver

Table 22 Standard Pads Class_A1+

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.		Max.		
Input leakage current	I_{OZA1+} CC	-1		1	µA	0 V ≤ V_{IN} ≤ V_{DDP}
Input high voltage	V_{IHA1+} SR	0.6 × V_{DDP}		V_{DDP} + 0.3	V	max. 3.6 V
Input low voltage	V_{ILA1+} SR	-0.3		0.36 × V_{DDP}	V	

Table 22 Standard Pads Class_A1+

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.		Max.		
Output high voltage, POD[1] = weak	V_{OHA1+} CC	V_{DDP} - 0.4		–	V	$I_{OH} \geq$ -400 µA
		2.4		–	V	$I_{OH} \geq$ -500 µA
Output high voltage, POD[1] = medium		V_{DDP} - 0.4		–	V	$I_{OH} \geq$ -1.4 mA
		2.4		–	V	$I_{OH} \geq$ -2 mA
Output high voltage, POD[1] = strong		V_{DDP} - 0.4		–	V	$I_{OH} \geq$ -1.4 mA
		2.4		–	V	$I_{OH} \geq$ -2 mA
Output low voltage	V_{OLA1+} CC	–		0.4	V	$I_{OL} \leq$ 500 µA; POD[1] = weak
		–		0.4	V	$I_{OL} \leq$ 2 mA; POD[1] = medium
		–		0.4	V	$I_{OL} \leq$ 2 mA; POD[1] = strong
Fall time	t_{FA1+} CC	–		150	ns	C_L = 20 pF; POD[1] = weak
		–		50	ns	C_L = 50 pF; POD[1] = medium
		–		28	ns	C_L = 50 pF; POD[1] = strong; edge = slow
		–		16	ns	C_L = 50 pF; POD[1] = strong; edge = soft;
Rise time	t_{RA1+} CC	–		150	ns	C_L = 20 pF; POD[1] = weak
		–		50	ns	C_L = 50 pF; POD[1] = medium
		–		28	ns	C_L = 50 pF; POD[1] = strong; edge = slow
		–		16	ns	C_L = 50 pF; POD[1] = strong; edge = soft

1) POD = Pin Out Driver

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Table 23 Standard Pads Class_A2

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.		Max.		
Fall time	t_{FA2} CC	–		150	ns	C_L = 20 pF; POD = weak
		–		50	ns	C_L = 50 pF; POD = medium
		–		3.7	ns	C_L = 50 pF; POD = strong; edge = sharp
		–		7	ns	C_L = 50 pF; POD = strong; edge = medium
		–		16	ns	C_L = 50 pF; POD = strong; edge = soft
Rise time	t_{RA2} CC	–		150	ns	C_L = 20 pF; POD = weak
		–		50	ns	C_L = 50 pF; POD = medium
		–		3.7	ns	C_L = 50 pF; POD = strong; edge = sharp
		–		7.0	ns	C_L = 50 pF; POD = strong; edge = medium
		–		16	ns	C_L = 50 pF; POD = strong; edge = soft

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3.2.7 Oscillator Pins

Note: It is strongly recommended to measure the oscillation allowance (negative resistance) in the final target system (layout) to determine the optimal parameters for the oscillator operation. Please refer to the limits specified by the crystal or ceramic resonator supplier.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

The oscillator pins can be operated with an external crystal (see **Figure 20**) or in direct input mode (see **Figure 21**).

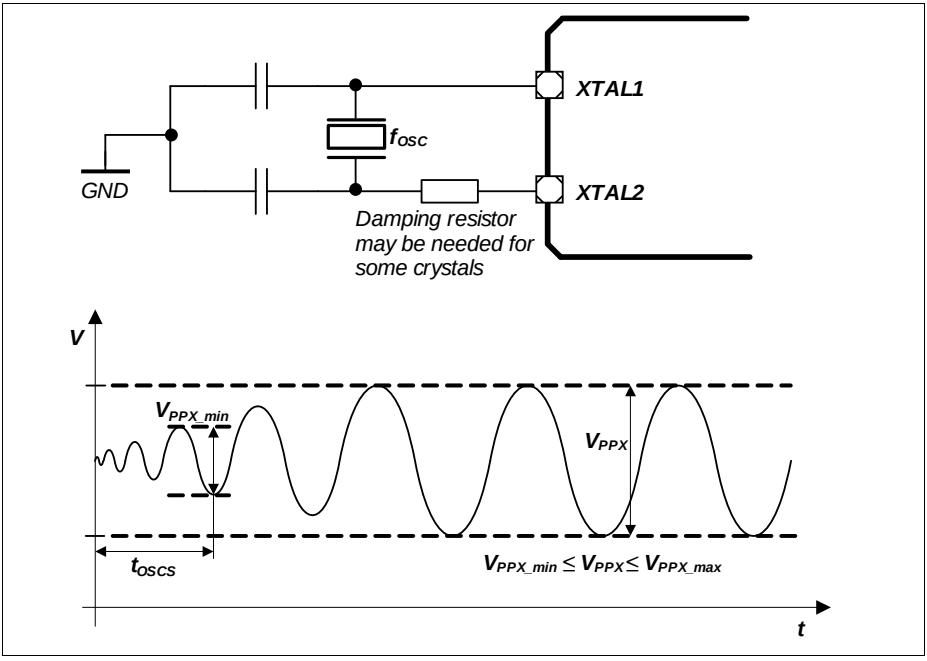

Figure 20 Oscillator in Crystal Mode

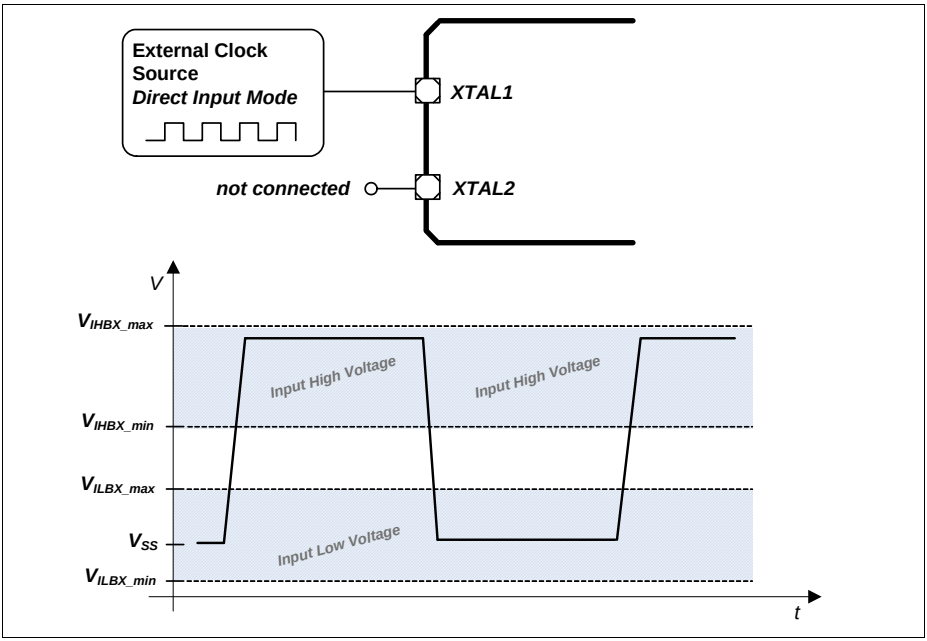

Figure 21 Oscillator in Direct Input Mode

3.3.2 Power-Up and Supply Monitoring

$\overline{\text{PORST}}$ is always asserted when V_{DDP} and/or V_{DDC} violate the respective thresholds.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

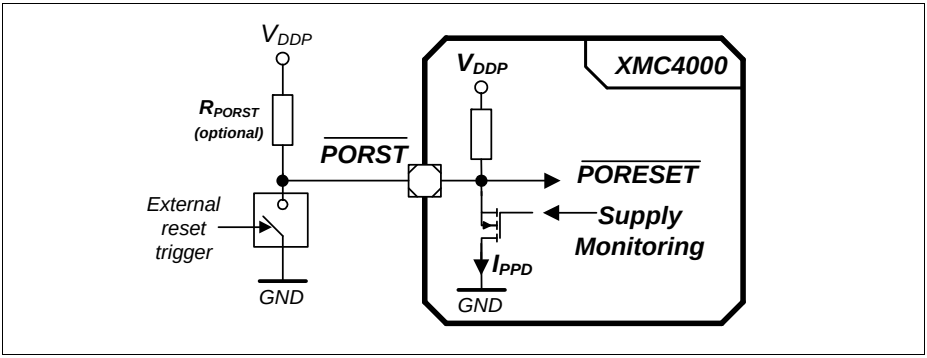

Figure 25 $\overline{\text{PORST}}$ Circuit

Table 37 Supply Monitoring Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Digital supply voltage reset threshold	V_{POR} CC	2.79[1]	–	3.05[2]	V	[3]
Core supply voltage reset threshold	V_{PV} CC	–	–	1.17	V	
V_{DDP} voltage to ensure defined pad states	V_{DDPPA} CC	–	1.0	–	V	
$\overline{\text{PORST}}$ rise time	t_{PR} SR	–	–	2	µs	[4]
Startup time from power-on reset with code execution from Flash	t_{SSW} CC	–	2.5	3.5	ms	Time to the first user code instruction
V_{DDC} ramp up time	t_{VCR} CC	–	550	–	µs	Ramp up after power-on or after a reset triggered by a violation of V_{POR} or V_{PV}

1) Minimum threshold for reset assertion.

3.3.6 JTAG Interface Timing

The following parameters are applicable for communication through the JTAG debug interface. The JTAG module is fully compliant with IEEE1149.1-2000.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Note: Operating conditions apply.

Table 42 JTAG Interface Timing Parameters

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
TCK clock period	t_1	SR	25	–	–	ns	
TCK high time	t_2	SR	10	–	–	ns	
TCK low time	t_3	SR	10	–	–	ns	
TCK clock rise time	t_4	SR	–	–	4	ns	
TCK clock fall time	t_5	SR	–	–	4	ns	
TDI/TMS setup to TCK rising edge	t_6	SR	6	–	–	ns	
TDI/TMS hold after TCK rising edge	t_7	SR	6	–	–	ns	
TDO valid after TCK falling edge[1] (propagation delay)	t_8	CC	–	–	13	ns	C_L = 50 pF
			3	–	–	ns	C_L = 20 pF
TDO hold after TCK falling edge[1]	t_{18}	CC	2	–	–	ns	
TDO high imped. to valid from TCK falling edge[1)2)]	t_9	CC	–	–	14	ns	C_L = 50 pF
TDO valid to high imped. from TCK falling edge[1]	t_{10}	CC	–	–	13.5	ns	C_L = 50 pF

1) The falling edge on TCK is used to generate the TDO timing.

2) The setup time for TDO is given implicitly by the TCK cycle time.

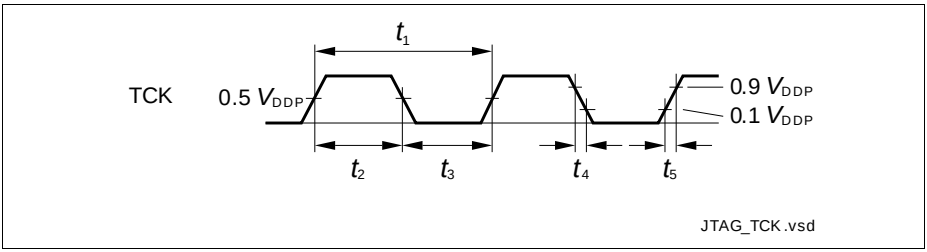

Figure 27 Test Clock Timing (TCK)

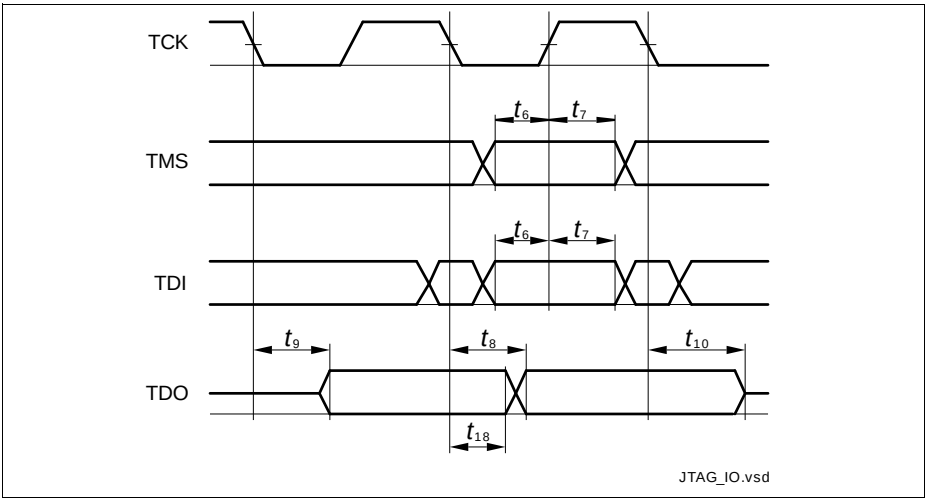

Figure 28 JTAG Timing

Full-Speed Input Path (Read)

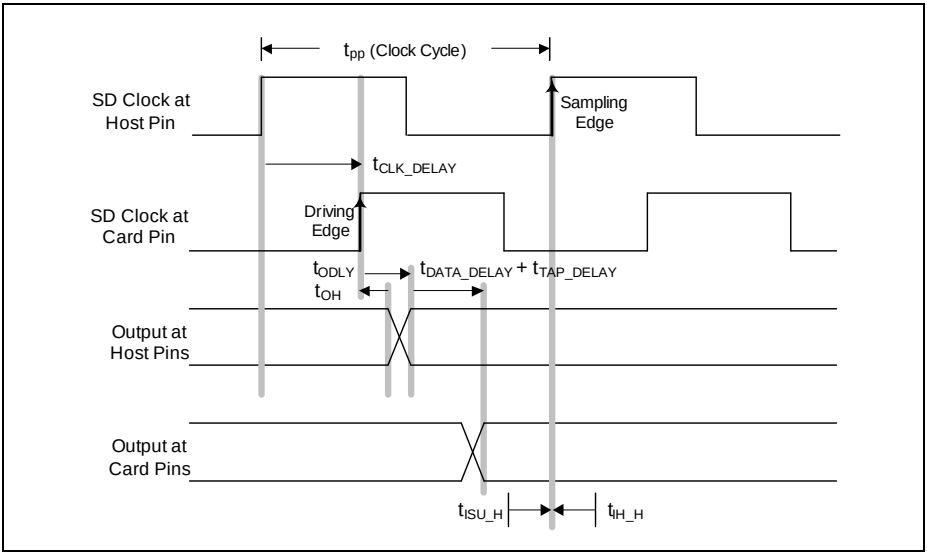

Figure 38 Full-Speed Input Path

Full-Speed Read Meeting Setup (Maximum Delay)

The following equations show how to calculate the allowed combined propagation delay range of the SD_CLK and SD_DAT/CMD signals on the PCB.

(5)

$$t_{CLK\_DELAY} + t_{DATA\_DELAY} + t_{TAP\_DELAY} + t_{ODLY} + t_{ISU\_F} < 0{,}5 \times t_{pp}$$

$$t_{CLK\_DELAY} + t_{DATA\_DELAY} < 0{,}5 \times t_{pp} - t_{ODLY} - t_{ISU\_F} - t_{TAP\_DELAY}$$

$$t_{CLK\_DELAY} + t_{DATA\_DELAY} < 20 - 14 - 2 - t_{TAP\_DELAY}$$

$$t_{CLK\_DELAY} + t_{DATA\_DELAY} < 4 - t_{TAP\_DELAY}$$

The data + clock delay can be up to 4 ns for a 40 ns clock cycle.

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High-Speed Input Path (Read)

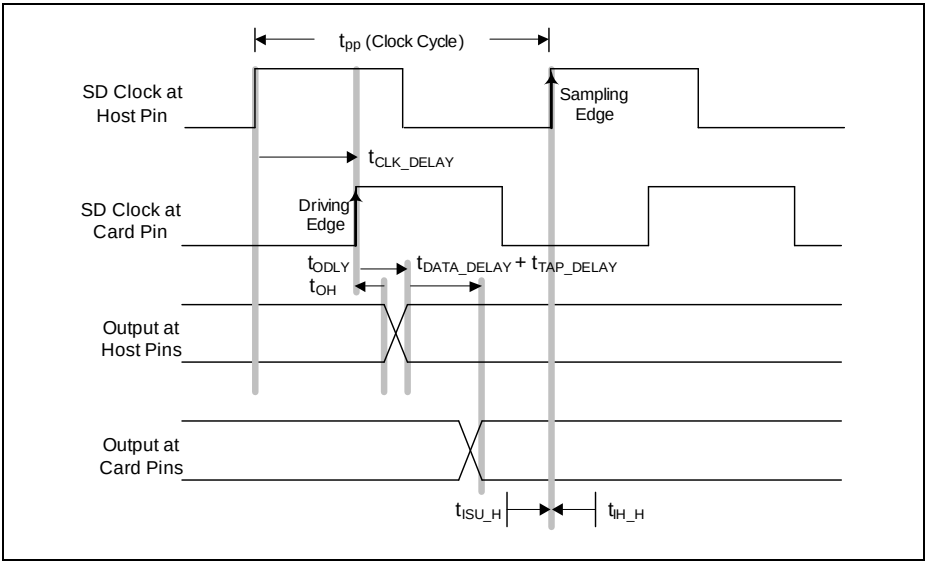

Figure 40 High-Speed Input Path

High-Speed Read Meeting Setup (Maximum Delay)

The following equations show how to calculate the allowed combined propagation delay range of the SD_CLK and SD_DAT/CMD signals on the PCB.

(11)

$$t_{CLK\_DELAY} + t_{DATA\_DELAY} + t_{TAP\_DELAY} + t_{ODLY} + t_{ISU\_H} < t_{pp}$$

$$t_{CLK\_DELAY} + t_{DATA\_DELAY} < t_{pp} - t_{ODLY} - t_{ISU\_H} - t_{TAP\_DELAY}$$

$$t_{CLK\_DELAY} + t_{DATA\_DELAY} < 20 - 14 - 2 - t_{TAP\_DELAY}$$

$$t_{CLK\_DELAY} + t_{DATA\_DELAY} < 4 - t_{TAP\_DELAY}$$

The data + clock delay can be up to 4 ns for a 20 ns clock cycle.

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3.3.10.2 EBU Burst Mode Access Timing

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Note: Operating Conditions apply, with Class A2 pins and C_L = 16 pF.

Table 59 EBU Burst Mode Read / Write Access Timing Parameters

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
Output delay from BFCLKO rising edge	t_{10}	CC	-2	–	2	ns	–
$\overline{RD}$ and RD/$\overline{WR}$ active/inactive after BFCLKO active edge[1]	t_{12}	CC	-2	–	2	ns	–
$\overline{CS}$x output delay from BFCLKO active edge[1]	t_{21}	CC	-2.5	–	1.5	ns	–
$\overline{ADV}$ active/inactive after BFCLKO active edge[2]	t_{22}	CC	-2	–	2	ns	–
$\overline{BAA}$ active/inactive after BFCLKO active edge[2]	t_{22a}	CC	-2.5	–	1.5	ns	–
Data setup to BFCLKI rising edge[3]	t_{23}	SR	3	–	–	ns	–
Data hold from BFCLKI rising edge[3]	t_{24}	SR	0	–	–	ns	–
$\overline{WAIT}$ setup (low or high) to BFCLKI rising edge[3]	t_{25}	SR	3	–	–	ns	–
$\overline{WAIT}$ hold (low or high) from BFCLKI rising edge[3]	t_{26}	SR	0	–	–	ns	–

1) An active edge can be a rising or falling edge, depending on the settings of bits BFCON.EBSE / ECSE and the clock divider ratio.
Negative minimum values for these parameters mean that the last data read during a burst may be corrupted. However, with clock feedback enabled, this value is an oversampling not required for the internal bus transaction, and will be discarded.

2) This parameter is valid for BUSCONx.EBSE = 1 and BUSAPx.EXTCLK = 00_B.
For BUSCONx.EBSE = 1 and other values of BUSAPx.EXTCLK, ADV and BAA will be delayed by 1/2 of the internal bus clock period $T_{CPU} = 1 / f_{CPU}$.
For BUSCONx. EBSE = 0 and BUSAPx.EXTCLK = 11_B, add 2 internal bus clock periods.
For BUSCONx. EBSE = 0 and other values of BUSAPx.EXTCLK, add 1 internal bus clock period.

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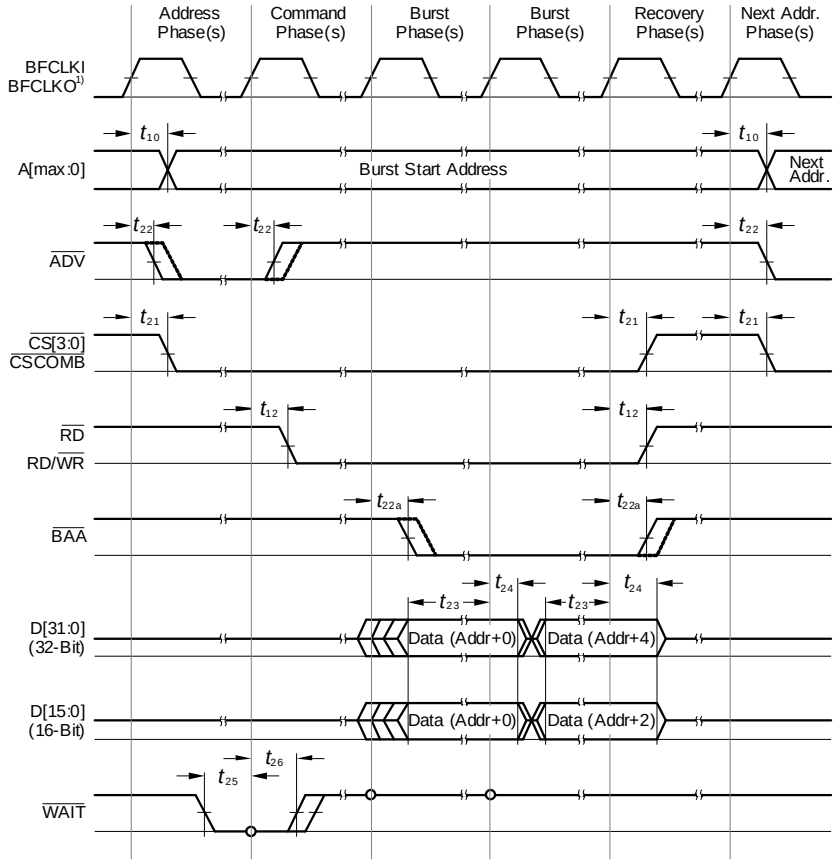
3) If the clock feedback is not enabled, the input signals are latched using the internal clock in the same way as for asynchronous access. Thus, t_5, t_6, t_7 and t_8 from the asynchronous timing apply.



1) Output delays are always referenced to BCLKO . The reference clock for input characteristics depends on bit EBU _BFCON.FDBKEN.
EBU_BFCON.FDBKEN= 0: BFCLKO is the input reference clock .
EBU_BFCON.FDBKEN= 1: BFCLKI is the input reference clock (EBU clock feedback enabled).

EBU_BurstRDWR.vsd

Figure 45 EBU Burst Mode Read / Write Access Timing

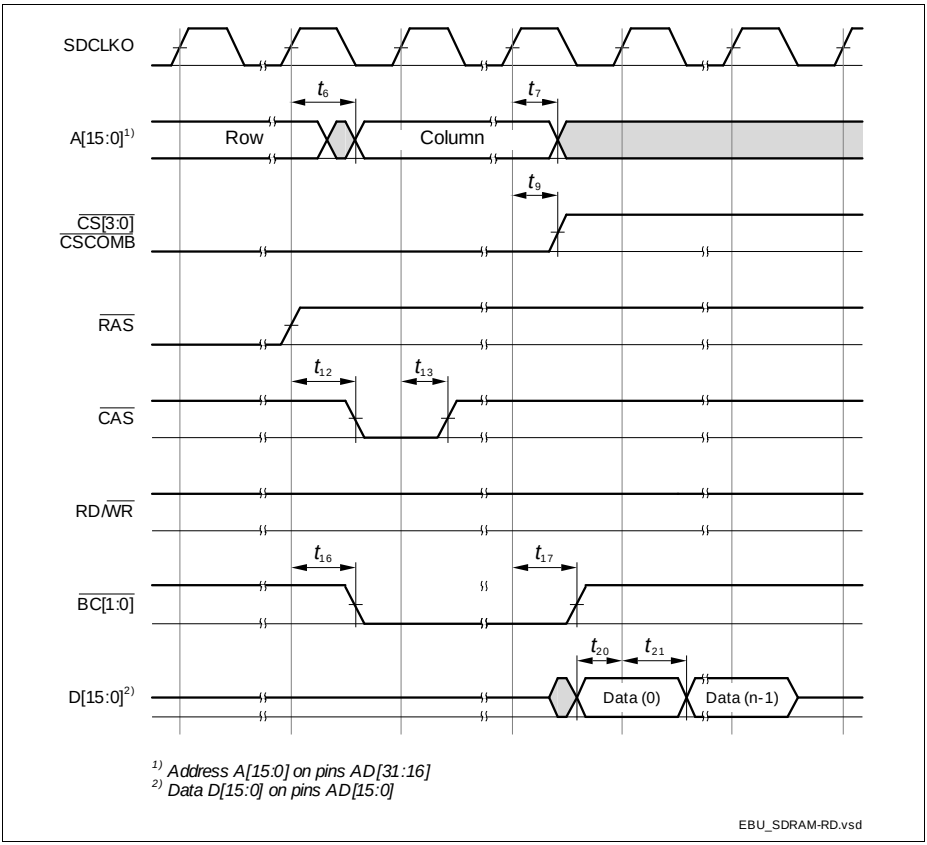


Figure 48 EBU SDRAM Read Access Timing

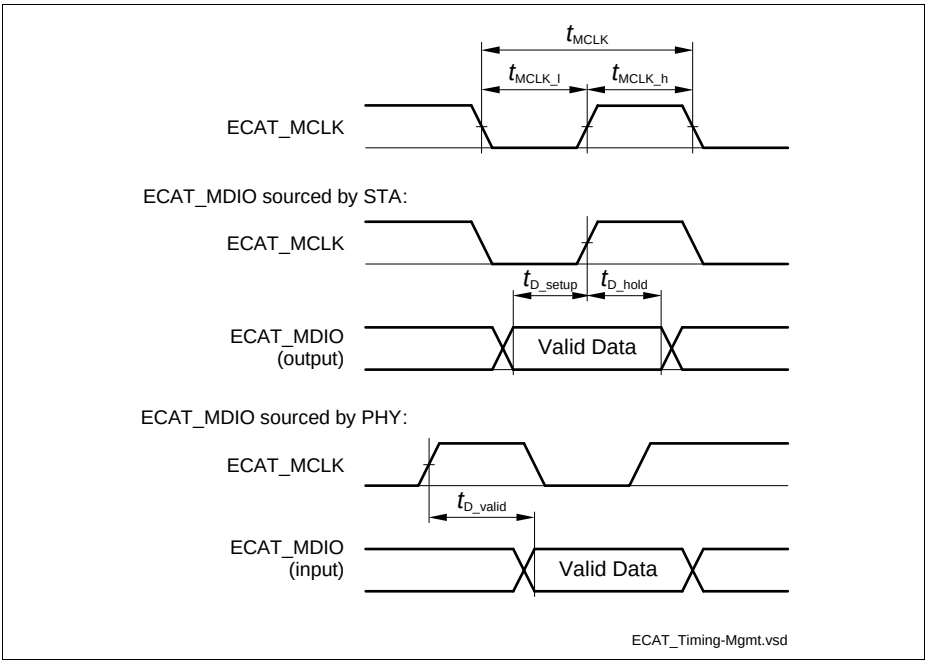


Figure 56 ECAT Management Signal Timing

3.3.13.3 MII Timing TX Characteristics

Table 68 ETH MII TX Signal Timing Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
PHY_CLK25, TX_CLK period	t_{TX_CLK} SR	–	40	–	ns	
Delay between PHY clock source PHY_CLK25 and TX_CLK output of the PHY	t_{PHY_delay} SR	–	–	–	ns	PHY dependent

3.3.13.4 MII Timing RX Characteristics

Table 69 ETH MII RX Signal Timing Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
RX_CLK period	t_{RX_CLK} SR	–	40	–	ns	C_L = 25 pF, IEEE802.3 requirement
RX_DV/RX_DV/RXD[3:0] valid before rising edge of RX_CLK	t_{RX_setup} SR	10	–	–	ns	
RX_DV/RX_DV/RXD[3:0] valid after rising edge of RX_CLK	t_{RX_hold} SR	10	–	–	ns	

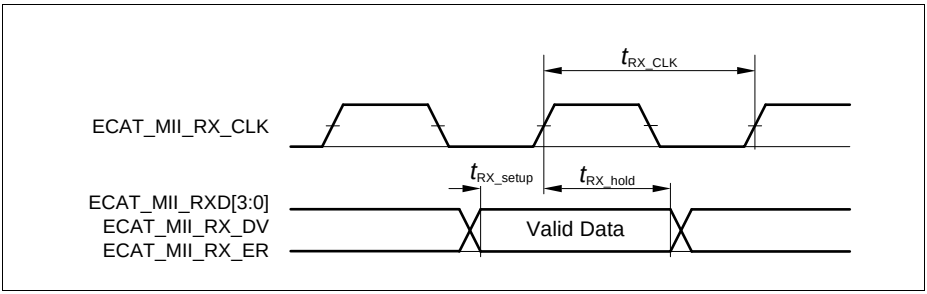


Figure 58 MII RX characteristics